

1MBI900VXA-120PC-54

IGBT Modules

IGBT MODULE (V series) 1200V / 900A / 1 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

NPC 3-level Inverter Inverter DB for Motor Drive AC and DC Servo Drive Amplifier (DB) Active PFC Industrial machines



■ Maximum Ratings and Characteristics

■ Maximum Ratings (at T_c=25°C unless otherwise specified)

Items Collector-Emitter voltage		Symbols	Conditions		Maximum ratings	Units V	
		Vces			1200		
Gate-Emitter voltage		V _{GES}			±20	V	
			Continuous	Tc=25°C	1200		
		Ic	Continuous	Tc=100°C	900		
		Ic pulse	1ms		1800	Α	
		-lc			120		
		-I _{C pulse}	1ms		240		
Collector Power Dissipation		Pc	1 device		5100	W	
Reverse voltage for FWD		V _R			1200	V	
Forword current for FWD		IF	Continuous		900	Α	
		I _{F pulse}	1ms		1800	A	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		Тјор			150	°C	
Case temperature		Tc		150 -40 ~ +150			
Storage temperature		T _{stg}					
Isolation voltage	between terminal and copper base (*1)	V _{iso}	AC : 1min.		4000	VAC	
	between thermistor and others (*2)	V iso	AC . IIIIII.		4000	VAC	
Screw Torque (*3)	Mounting	-	M5		6.0	N m	
	Main Terminals	-	M8		10.0		
	Sense Terminals	-	M4		2.1		

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable Value : Mounting 3.0 ~ 6.0 Nm (M5)

Recommendable Value : Main Terminals 8.0 ~ 10.0 Nm (M8)

Recommendable Value : Sense Terminals 1.8 ~ 2.1 Nm

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● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
		Syllibols			min.	typ.	max.	Ullits
	Zero gate voltage collector current	Ices	V _{CE} = 1200V V _{GE} = 0V		-	-	8.0	mA
	Gate-Emitter leakage current	IGES	V _{CE} = 0V V _{GE} =±20V		-	-	1600	nA
	Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} = 20V I _C = 900mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	.,	Ic = 900A V _{GE} =15V	T _j = 25°C	-	1.75	2.20	
GBT/Inverse Diode		V _{CE(sat)} (terminal) (*4)		T _j =125°C	-	2.10	-	
		(terrillial) (4)		T _j =150°C		2.15	-	.,
		.,		T _j = 25°C	-	1.65	2.10	V
		V _{CE(sat)}		T _j =125°C	-	2.00	-	
		(chip)		T _j =150°C		2.05	-	
	Internal gate resistance	R _G (int)	-	<u>'</u>		1.19	-	Ω
	Input capacitance	Cies	V _{CE} =10V, V _{GE} =0V,f	-	83	-	nF	
37		ton	Vcc = 600V		-	1100	-	
IGE	Turn-on time	tr	Ic = 900A		-	500	-	nsec
		t _{r (i)}	V _{GE} = ±15V	-	150	-		
	Turn-off time	toff	$R_G = 1.6 \Omega$	-	1200	-		
		tr	Ls = 70nH	-	150	-		
	Forward on voltage	.,		T _j = 25°C	-	1.70	2.15	V
		V _F (terminal) (*4)	I _F = 120A V _{GE} =0V	T _j =125°C	-	1.80	-	
		(terminal) ('4)		T _j =150°C		1.75	-	
		.,		T _j = 25°C	-	1.65	2.10	
		V _F (chip)		T _j =125°C	-	1.75	-	
		(Criip)		T _j =150°C		1.70	-	
	Reverse Current	I _R	V _{CE} = 1200V	V _{CE} = 1200V		-	8.0	mA
	Forward on voltage	.,	I _F = 900A V _{GE} =0V	T _j = 25°C	-	1.70	2.15	- V
F		V _F (terminal) (*4)		T _j =125°C	-	1.80	-	
		(terrillial) (4)		T _j =150°C		1.75	-	
		.,		T _j = 25°C	-	1.60	2.05	
		V _F (chip)		T _j =125°C	-	1.70	-	
		(Criip)		T _j =150°C		1.65	-	
	Reverse recovery time	trr	I _F = 900A		-	200	-	nsec
stor	Resistance	R	T = 25°C T = 100°C		-	5000	-	Ω
Thermistor		K			465	495	520	122
The	B value	alue B T = 25/50°C		3305	3375	3450	K	

Note *4: Please refer to page 8, there is definition of on-state voltage at terminal.

Thermal resistance characteristics

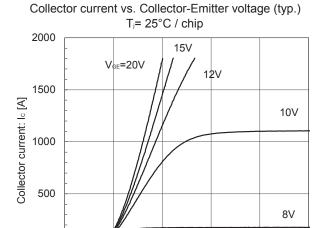
Items	Symbols	Conditions	Characteristics			Units	
items	Symbols	Conditions	min.	typ.	max.	Ullits	
	R _{th(j-c)}	Inverter IGBT	-	-	0.030		
Thermal resistance (1device)		Inverse Diode	-	-	0.250	°C/W	
		FWD	-	-	0.033	C/VV	
Contact thermal resistance (1device) (*5) Rth(c-f)		with Thermal Compound	-	0.00625	-		

Note *5 : This is the value which is defined mounting on the additional cooling fin with thermal compound.

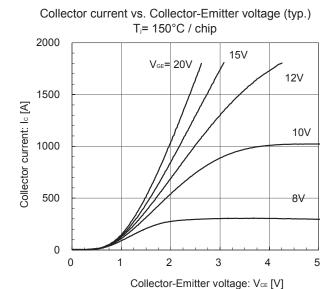
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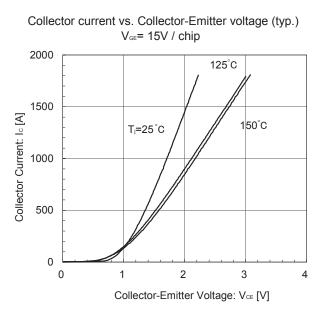
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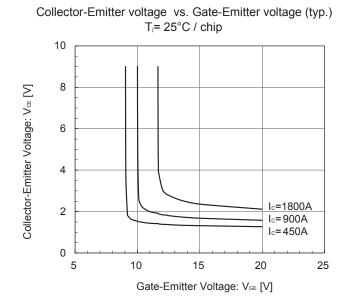
■ Characteristics (Representative)

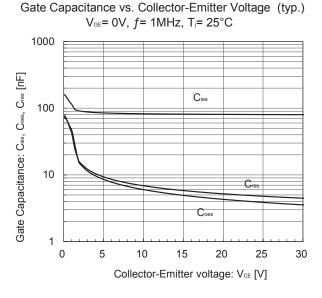


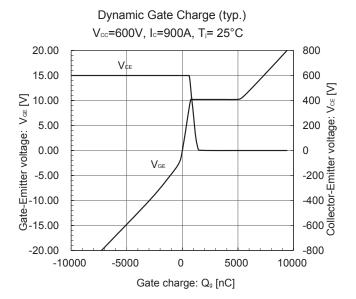
Collector-Emitter voltage: VCE [V]



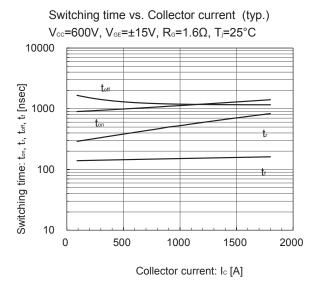


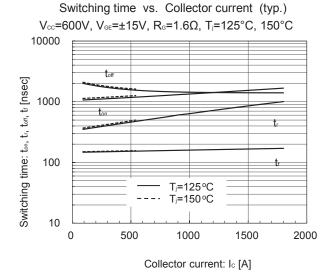


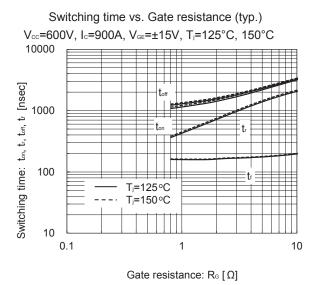


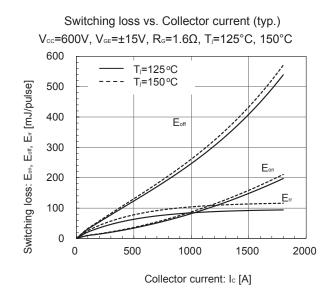


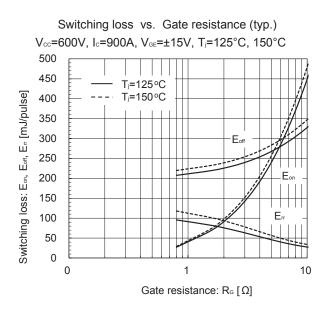
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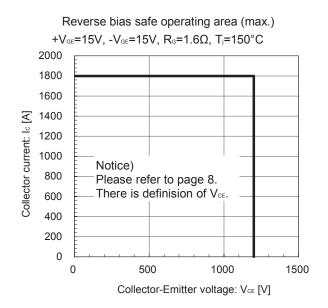


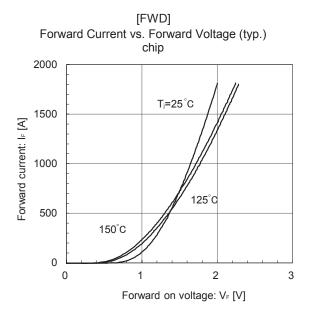




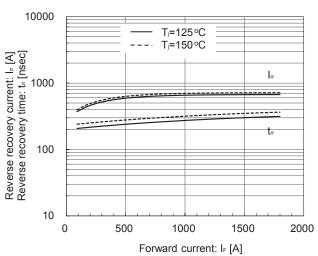








 $[FWD] $$ Reverse Recovery Characteristics (typ.) $$ V_{cc}=600V, V_{ge}=\pm15V, R_{g}=1.6\Omega, T_{j}=125^{\circ}C, 150^{\circ}C $$$



FWD safe operating area (max.)

T_j=150°C

Pmax=900kW

1000
Please refer to page 8.
There is definision of V_{CE}.

600

0

200

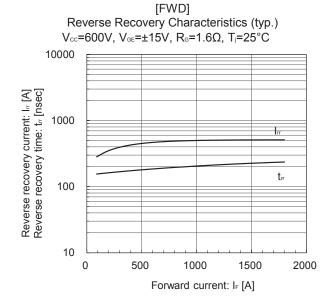
400

800

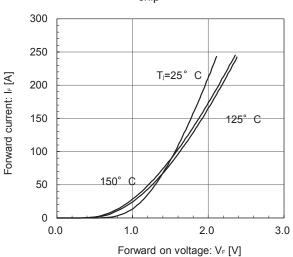
Collector-Emitter voltage: Vce [V]

1000 1200

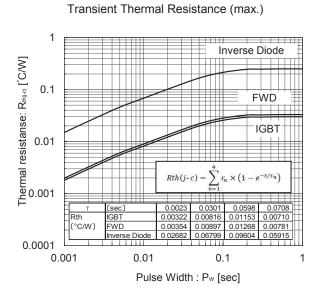
[FWD]

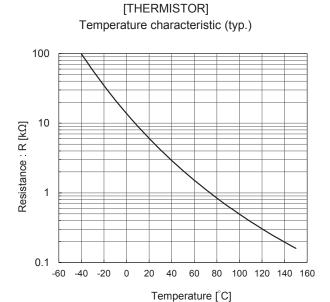


[Inverse Diode]
Forward Current vs. Forward Voltage (typ.)
chip

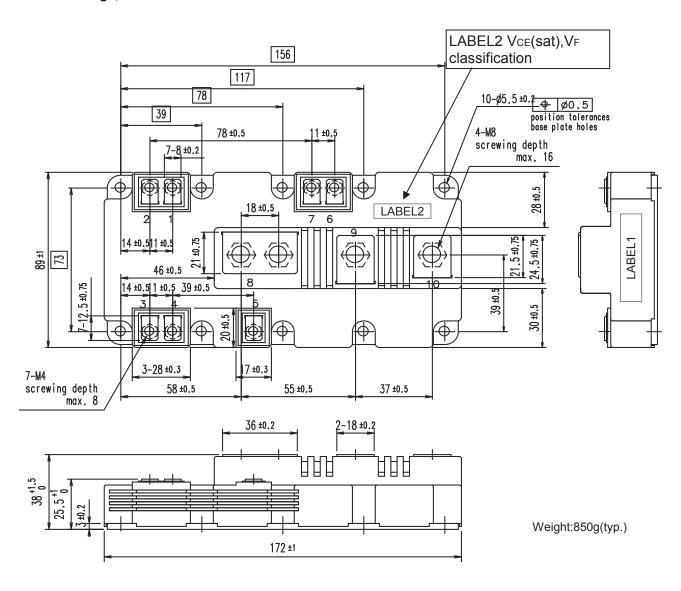


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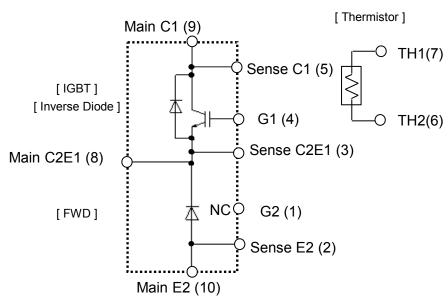




■ Outline Drawings, mm

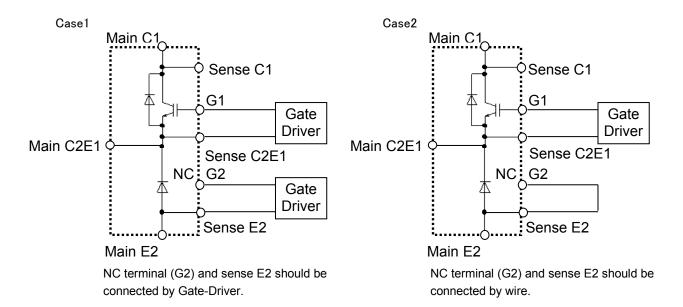


■ Equivalent Circuit Schematic



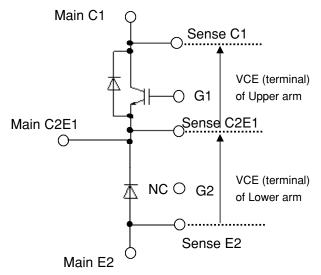
Notice) There is recommendation of wiring for NC terminal as follows

■ Fuji recommends wire connection of CASE1 or CASE2 to fix NC terminal voltage.



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■ Definition of on-state voltage at terminal and switching characteristics



Fuji defined VCE value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm.

Switching characteristics of VCE also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm.

Please use these terminals whenever measure spike voltage and on-state voltage.

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- OA equipment
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- Measurement equipment

- Machine tools
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